

Excellent Integrated System Limited

Stocking Distributor

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<u>Vishay Semiconductor/Diodes Division</u> <u>VBT3080C-M3/8W</u>

For any questions, you can email us directly: sales@integrated-circuit.com

Distributor of Vishay Semiconductor/Diodes Division: Excellent Integrated System Limite

Datasheet of VBT3080C-M3/8W - DIODE SCHOTTKY 30A 80V TO-263AB

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www.vishay.com

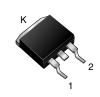
VBT3080C-M3

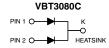
Vishay General Semiconductor

Dual Trench MOS Barrier Schottky Rectifier

Ultra Low $V_F = 0.46 \text{ V}$ at $I_F = 5 \text{ A}$

TMBS[®]





PRIMARY CHARACTERISTICS				
Package	TO-263AB			
I _{F(AV)}	2 x 15 A			
V _{RRM}	80 V			
I _{FSM}	150 A			
V _F at I _F = 15 A	0.65 V			
T _J max.	150 °C			
Diode variation	Common cathode			

FEATURES

- Trench MOS Schottky technology
- · Low forward voltage drop, low power losses

High efficiency operation

COMPLIANT HALOGEN

- Meets MSL level 1, per J-STD-020, LF maximum peak of 245 °C
- Material categorization: For definitions of compliance please see www.vishay.com/doc?99912

TYPICAL APPLICATIONS

For use in high frequency converters, switching power supplies, freewheeling diodes, OR-ing diode, DC/DC converters, and reverse battery protection.

MECHANICAL DATA

Case: TO-263AB

Molding compound meets UL 94 V-0 flammability rating Base P/N-M3 - halogen-free, RoHS-compliant, and

commercial grade

Terminals: Matte tin plated leads, solderable per

J-STD-002 and JESD 22-B102

M3 suffix meets JESD 201 class 1A whisker test

Polarity: As marked

Mounting Torque: 10 in-lbs maximum

MAXIMUM RATINGS (T _A = 25 °C unless otherwise noted)					
PARAMETER		SYMBOL	VBT3080C	UNIT	
Maximum repetitive peak reverse voltage		V _{RRM}	80	V	
Maximum average forward rectified current (fig. 1)	per device	I _{F(AV)}	30	А	
	per diode		15		
Peak forward surge current 8.3 ms single half sine-wave superimposed on rated load per diode		I _{FSM}	150	А	
Operating junction and storage temperature range		T _J , T _{STG}	- 55 to + 150	°C	

ELECTRICAL CHARACTERISTICS (T _A = 25 °C unless otherwise noted)						
PARAMETER	TEST CO	TEST CONDITIONS		TYP.	MAX.	UNIT
Instantaneous forward voltage per diode ⁽¹⁾	I _F = 5 A	T _A = 25 °C	V _F	0.52	-	· V
	I _F = 7.5 A			0.58	-	
	I _F = 15 A			0.75	0.82	
	I _F = 5 A	T _A = 125 °C		0.46	-	
	I _F = 7.5 A			0.52	-	
	I _F = 15 A			0.65	0.70	
Reverse current per diode (2)	V - 90 V	T _A = 25 °C T _A = 125 °C	I _R	30	700	μΑ
	V _R = 80 V			20	35	mA

Notes

(1) Pulse test: 300 µs pulse width, 1 % duty cycle

(2) Pulse test: Pulse width \leq 40 ms

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VBT3080C-M3

Vishay General Semiconductor

THERMAL CHARACTERISTICS (T _A = 25 °C unless otherwise noted)					
PARAMETER	SYMBOL	VBT3080C	UNIT		
Typical thermal resistance	per diode	$R_{ hetaJC}$	2.5	°C/W	
	per device		2.0]	

ORDERING INFORMATION (Example)						
PACKAGE	PREFERRED P/N	UNIT WEIGHT (g)	PACKAGE CODE	BASE QUANTITY	DELIVERY MODE	
TO-263AB	VBT3080C-M3/4W	1.39	4W	50/tube	Tube	
TO-263AB	VBT3080C-M3/8W	1.39	8W	800/reel	Tape and reel	

RATINGS AND CHARACTERISTICS CURVES

(T_A = 25 °C unless otherwise noted)

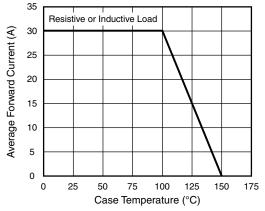


Fig. 1 - Maximum Forward Current Derating Curve

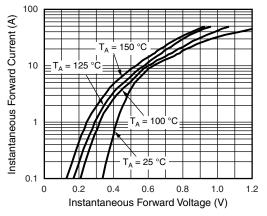


Fig. 3 - Typical Instantaneous Forward Characteristics Per Diode

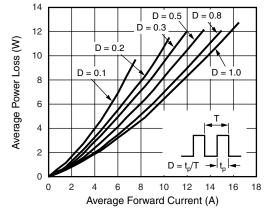


Fig. 2 - Forward Power Loss Characteristics Per Diode

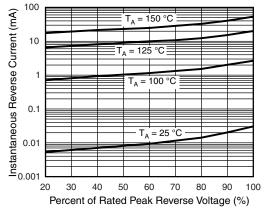


Fig. 4 - Typical Reverse Characteristics Per Diode

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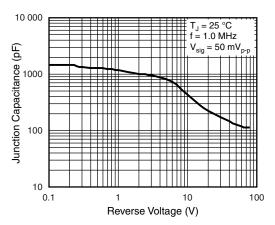


Fig. 5 - Typical Junction Capacitance Per Diode

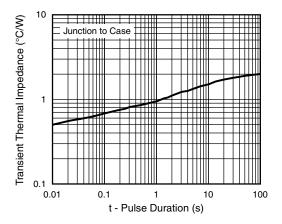


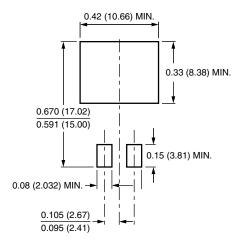
Fig. 6 - Typical Transient Thermal Impedance Per Device

PACKAGE OUTLINE DIMENSIONS in inches (millimeters)

TO-263AB

0.411 (10.45) 0.190 (4.83) 0.380 (9.65) 0.055 (1.40) 0.160 (4.06) 0.245 (6.22) 0.045 (1.14) MIN. 0.055 (1.40) 0.360 (9.14) 0.047 (1.19) 0.320 (8.13) 0.624 (15.85) K 0.591 (15.00) -0 to 0.01 (0 to 0.254) <u>0.110 (2.79)</u> <u>†</u> 0.090 (2.29) 0.037 (0.940) 0.021 (0.53) 0.027 (0.686) 0.014 (0.36) 0.105 (2.67) 0.140 (3.56) 0.095 (2.41) 0.205 (5.20) 0.110 (2.79) 0.195 (4.95)

Mounting Pad Layout





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